



DMG2305UX

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	Package	Ι _D T _A = +25°C
-20V	$52m\Omega @V_{GS} = -4.5V$	SOT23	-5.0A
-200	100mΩ $@V_{GS} = -2.5V$	30123	-3.6A

Description

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- **Power Management Functions**
- **DC-DC** Converters
- Motor Control

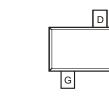
Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

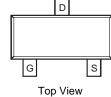
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (approximate)





Top View



Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMG2305UX-7	Standard	SOT23	3000/Tape & Reel
DMG2305UX-13	Standard	SOT23	10000/Tape & Reel

Internal Schematic

Drain

Gate

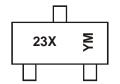
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



23X = Product Type Marking Code

- YM = Date Code Marking Y = Year (ex: W = 2009)
- M = Month (ex: 9 = September)

Date Code Kev

Year	200	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Y	2	7	А		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage		V _{DSS}	-20	V	
Gate-Source Voltage	V _{GSS}	±8	V		
	Steady State	T _A = +25°C T _A = +70°C	ID	-4.2 -3.3	A
Continuous Drain Current (Note 5) $V_{GS} = -4.5V$	t<10s	T _A = +25°C T _A = +70°C	ID	-5.0 -4.0	A
Pulsed Drain Current (Note 6)		I _{DM}	-10	A	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	90	°C/W
merma Resistance, Junction to Ambient (Note 5)	t<10s		64	°C/W
Thermal Resistance, Junction to Case (Note 7)	R _{θJC}	33	°C/W	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

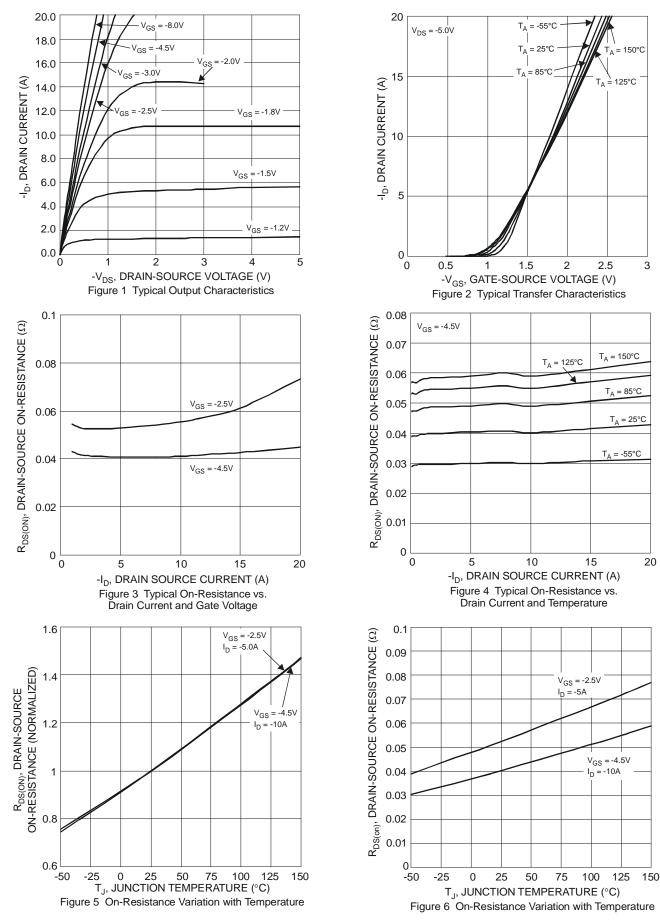
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}	_		-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_		±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)			-	-		
Gate Threshold Voltage	V _{GS(th)}	-0.5	_	-0.9	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
			40	52		$V_{GS} = -4.5V, I_D = -4.2A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	52	100	mΩ	$V_{GS} = -2.5V, I_D = -3.4A$
			68	200		$V_{GS} = -1.8V, I_D = -2A$
Forward Transfer Admittance	Y _{fs}	_	9	_	s	$V_{DS} = -5V, I_D = -4A$
DYNAMIC CHARACTERISTICS (Note 8)						-
Input Capacitance	Ciss	_	808	_	pF	
Output Capacitance	Coss	_	85		pF	V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	77		pF	T = T.000112
Gate Resistance	R _G		15.2		Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$
SWITCHING CHARACTERISTICS (Note 8)						
Total Gate Charge	Qg		10.2	_	nC	
Gate-Source Charge	Q _{gs}	_	1.3		nC	V _{GS} = -4.5V, V _{DS} = -4V, In = -3.5A
Gate-Drain Charge	Q _{gd}	_	2.2		nC	$I_{\rm D} = -3.5 {\rm A}$
Turn-On Delay Time	t _{D(on)}	_	10.8		ns	
Turn-On Rise Time	tr	_	13.7		ns	$V_{DS} = -4V, V_{GS} = -4.5V,$
Turn-Off Delay Time	t _{D(off)}	_	79.3	_	ns	$R_G = 6\Omega, I_D = -1A$
Turn-Off Fall Time	t _f	_	34.7	_	ns	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

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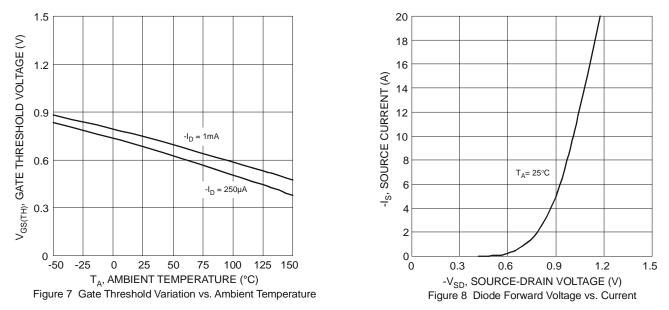


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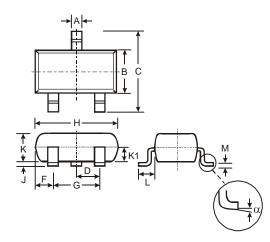


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Package Outline Dimensions

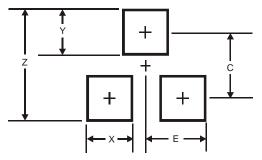
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
с	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
κ	0.903	1.10	1.00				
K1	-	-	0.400				
L	0.45	0.61	0.55				
М	0.085	0.18	0.11				
α	0°	8°	-				
All	Dimens	ions in	mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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